



A Product Line of **Diodes Incorporated**

LITE-ON SEMICONDUCTOR

RTT410(I_S)

A²S

°C

			ΓI	141	<u>J(L3)</u>
GLASS PASSIVATED BRIDGE RECTIFIE	RS	REVERSE VOLTAG		000 Vol Amper	
GENERAL DESCRIPTION Suitable for AC-to-DC bridge full wave rectification for SMPS,LED lighting, adapters, battery chargers appliances, office equipment, and telecommunication	s, home	I	<u>T</u>		
 FEATURES Rated at 1000V PRV Ideal for printed circuit board Reliable construction utilizing molded plastic technique Qualification is according to AEC-Q101 Rev_C Lead-Free Finish; RoHS Compliant (Notes 1 & Halogen and Antimony Free. "Green" Device (MECHANICAL DATA Case Material: "Green" Molding compound, UL flammability classification 94V-0, "Halogen-free". Polarity indicator: As marked on body Marking : RTT410 Lead free Sensitivity: Level 1 per J-STD-020 Weight: 0.389 grams (Approximate) 			DIM A A1 A2 C D E E1 L b e All dime	IT MIN 1.45 0.00 1.45 0.15 10.05 6.85 9.75 0.45 1.30 4.90	MAX 1.80 0.15 1.65 0.35 10.35 7.15 10.05 0.95 1.50 5.10 nillimeter
MAXIMUM RATINGS AND ELECTRICAL CHARAC Ratings at 25°C ambient temperature unless otherwise					
ABSOLUTE RATINGS					
PARAMETER	SYMBOL	VALUE	VALUE		
Maximum repetitive peak reverse voltage	V _{RRM}	1000			V
Maximum DC blocking voltage	V _{DC}	1000			V
Average rectified forward current Tc=100	C I _(AV)	4			A
Peak forward surge 8.3ms single half sine-wave	I _{FSM}	100			A

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST C	TEST CONDITION		ТҮР	MAX	UNIT			
Forward voltage (Note 4)	I _F = 4A	T _J = 25°C T _J = 125°C	V _F	 1.1	1.3	V			
Reverse leakage current	V _R =1000V	T _J = 25°C T _J = 125°C	I _R	 61	5 200	uA			
Typical junction capacitance (Note 5)		CJ	42		pF				

1²t

 T_j, T_{STG}

41.5

-55 ~ +150

THERMAL CHARACTERISTICS

I²t Rating for fusing (1ms<t<8.3ms)

Operating and Storage temperature range

PARAMETER	SYMBOL	ТҮР	UNIT	
Typical thermal resistance (Note 6,7)	RthJ _c	5	° C/W	
Typical thermal resistance (Note 0,7)	RthJ∟	8	0/11	

DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MAX		UNIT
Reverse recovery time	I _F = 0.5A, I _{rr} =0.25A, I _R =1.0A	T _{rr}	250		ns
Note : (1) EU Directive 2002/95/EC (RoHS), 2011/6	REV4, Oct-202	21, KBEA01			

Note:
(1) EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied.
(2). See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
(3). Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
(4) 300us pulse width , 2% duty cycle
(5) Measured at 1.0MHz and applied reverse voltage of 4.0 V DC
(6) Thermal Resistance test performed in accordance with JESD-51

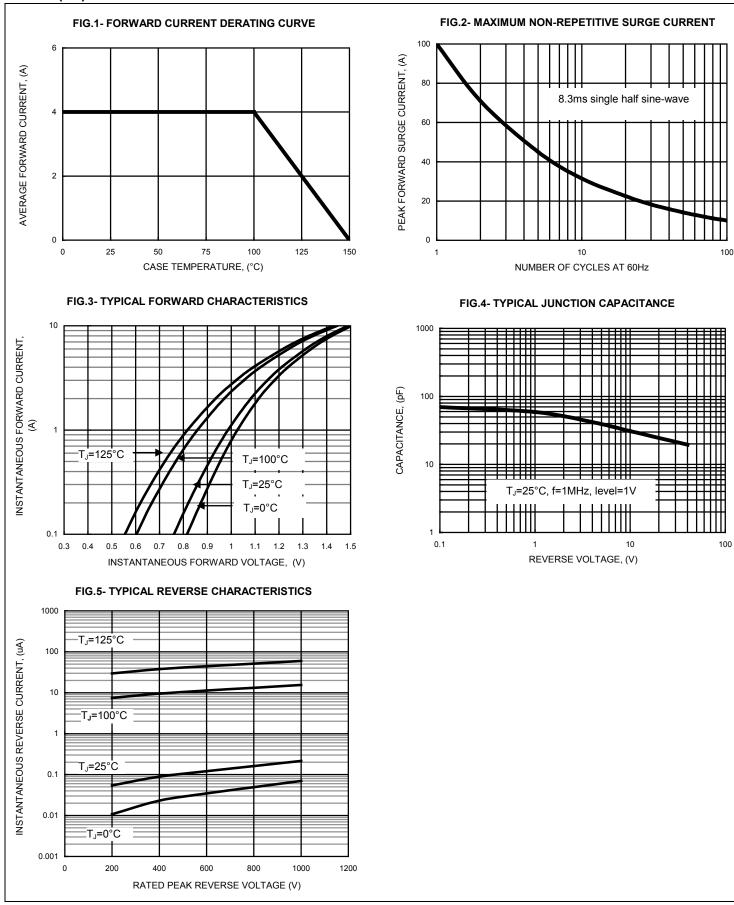
(6) Thermal Resistance test performed in accordance with JESD-51.

(7) The unit mounted P.B.C(50mm*50mm)+Test door open + fan Rated current



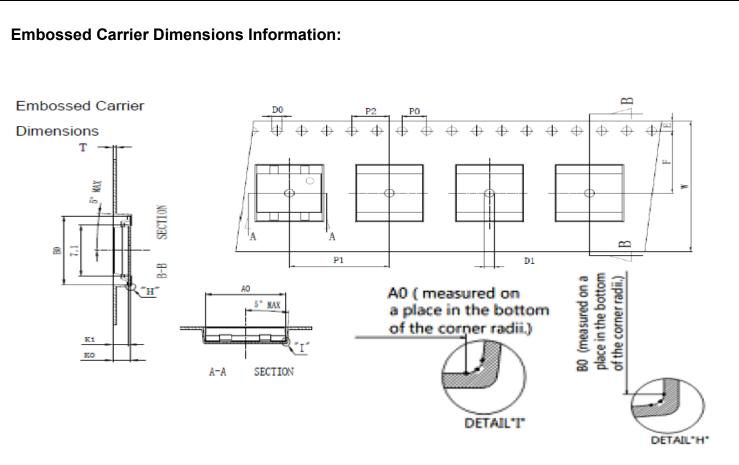
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EMBOSSED TYPE

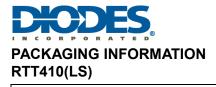
ALL DIMENSION IN MILLIMETERS AND (INCHES)

TAPE SIZE	AO	BO	KO	PO	P1	P2	Т
24mm	10.55±0.10	10.30±0.10	2.05±0.10	4.00±0.10	16.00±0.10	2.00±0.10	0.30±0.05
	• •		• •				
PRODUCT	E	F	DO	D1	W	10PO	K1

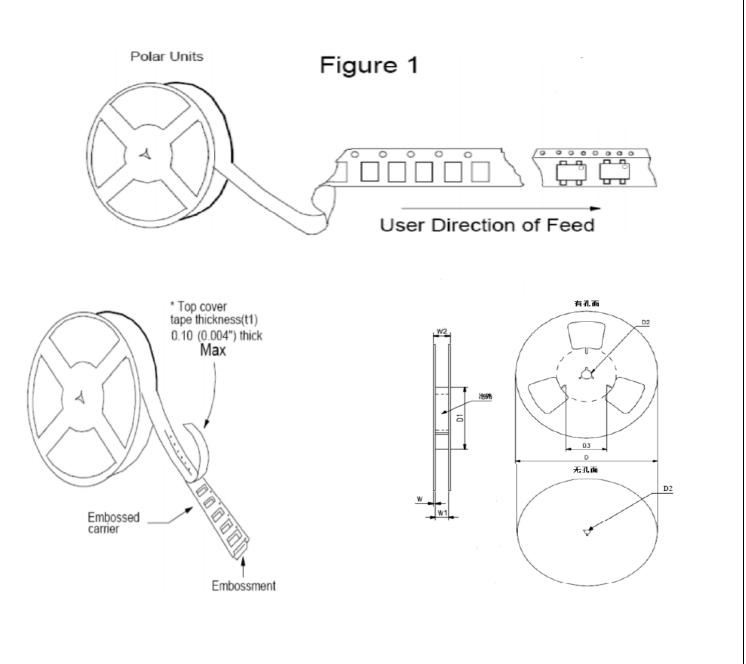
TYPE	E	F	DO	D1	W	10PO	K1
TT	1.75±0.10	11.50±0.10	1.50±0.10	1.50±0.10	24.0±0.30	40.0±0.20	1.90±0.10

REMARKS:

- 1. ALL other requirements not mentioned here to fulfill EIA-481-D
- 2. AO&BO measure on a place in the bottom of comer radii (see DETAIL"I" and DETIL"H")
- 3. KO measured from a place on the inside bottom of the pocket to top surface of carrier
- 4. P2 and F are measured from centerline of sprocket hole to centerline of pocket
- 5. 10 Sprocket hole pitch cumulative tolerance is ± 0.20 mm
- 6. Unless otherwise specified RO.2max
- 7. Surface resistivity of carrier tape should be within 10-4-10-8 Ω/square where the relative humidity is under 60% and the temperature is in between 20°C to 26



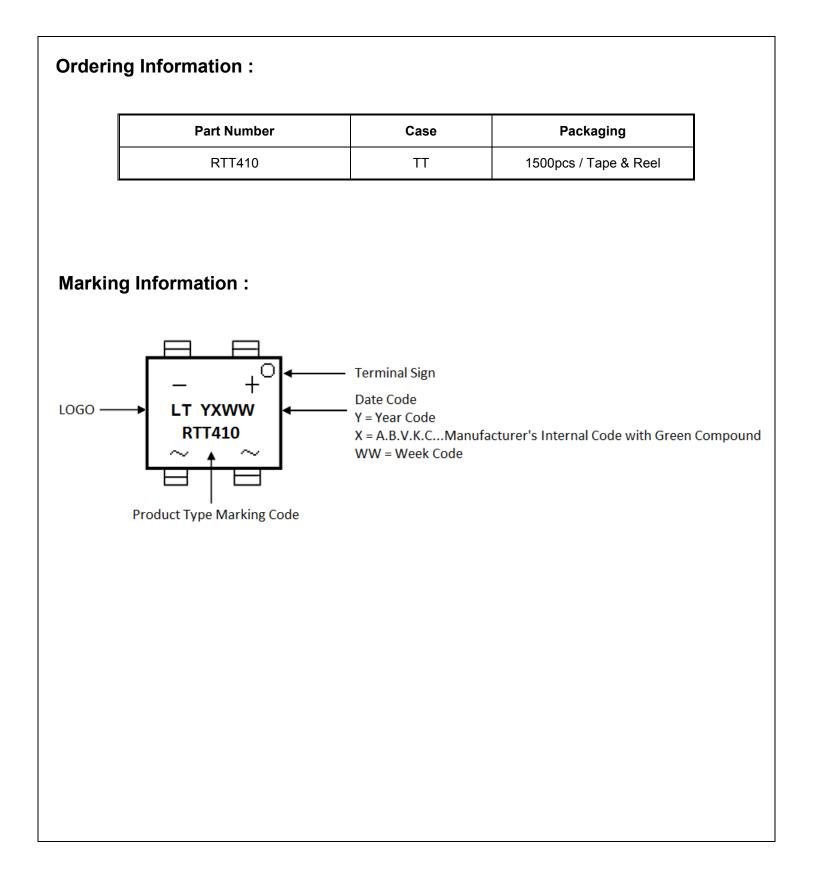
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REEL DIMENSIONS

TAPE SIZE	D	D1	D2	D3		W	W1	W2
24mm	330±2.0	100±2.0	13.0±0.2	75.0±2	2.0	2.30±0.2	2 24.4±2.0	<31
DEVICE	Q'TY/REEL	REEL DI					CARTON SIZE	Q'TY/CARTON
TYPE	(PCS)	(mm)	(mn	(mm) (PCS) (mm)		(PCS)		
ТТ	1500	330	335X335X32 1500 360X350X360		15000			
		•	1					•







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